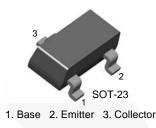
October 2014



BC846 / BC847 / BC848 / BC850 NPN Epitaxial Silicon Transistor

Features

- Switching and Amplifier Applications
- Suitable for Automatic Insertion in Thick and Thin-film Circuits
- Low Noise: BC850
- Complement to BC856, BC857, BC858, BC859, and BC860



Ordering Information⁽¹⁾

Part Number	Marking	Package	Packing Method
BC846AMTF	8AA	SOT-23 3L	Tape and Reel
BC846BMTF	8AB	SOT-23 3L	Tape and Reel
BC846CMTF	8AC	SOT-23 3L	Tape and Reel
BC847AMTF	8BA	SOT-23 3L	Tape and Reel
BC847BMTF	8BB	SOT-23 3L	Tape and Reel
BC847CMTF	8BC	SOT-23 3L	Tape and Reel
BC848BMTF	8CB	SOT-23 3L	Tape and Reel
BC848CMTF	8CC	SOT-23 3L	Tape and Reel
BC850AMTF	8EA	SOT-23 3L	Tape and Reel
BC850CMTF	8EC	SOT-23 3L	Tape and Reel

Note:

1. Affix "-A,-B,-C" means h_{FE} classification. Affix "-M" means SOT-23 package. Affix "-TF" means the tape and reel type packing.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter		Value	Unit
		BC846	80	
V _{CBO}	V _{CBO} Collector-Base Voltage	BC847 / BC850	50	V
		BC848	30	
	Collector-Emitter Voltage	BC846	65	
V _{CEO}		BC847 / BC850	45	V
		BC848	30	
V	Emitter Dese Veltere	BC846 / BC847	6	V
V _{EBO}	Emitter-Base Voltage	BC848 / BC850	5	v
Ι _C	Collector Current (DC)		100	mA
TJ	Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-65 to +150	°C

Thermal Characteristics⁽²⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
р	Power Dissipation	310	mW
P _D	Derate Above 25°C	2.48	mW/°C
R _{θJA}	Thermal Resistance, Junction-to-Ambient	403	°C/W

Note:

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

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Electrical Characteristics⁽³⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

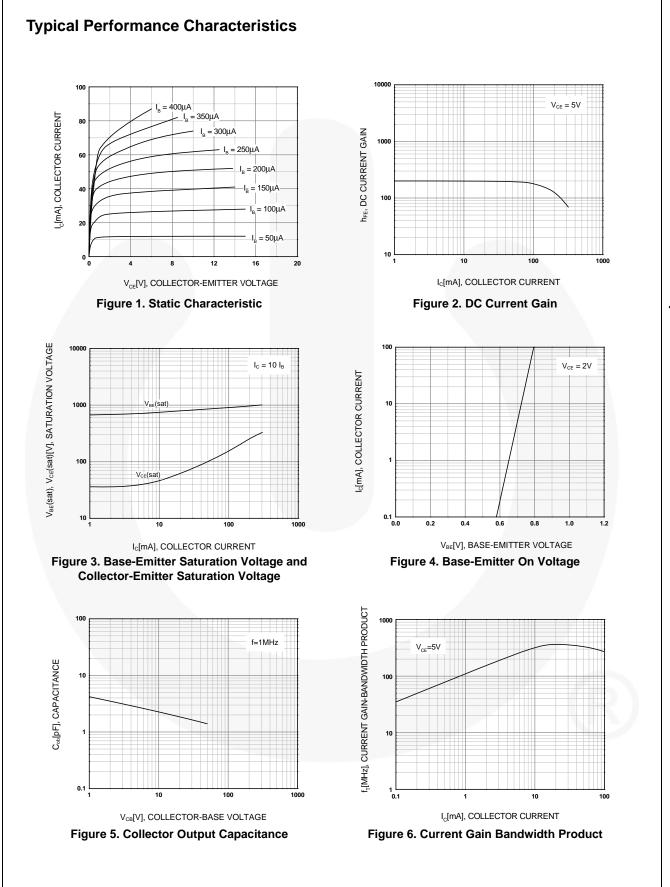
Symbol	Parameter		Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-Off Current		V _{CB} = 30 V, I _E = 0			15	nA
h _{FE}	DC Current Gain		V _{CE} = 5 V, I _C = 2 mA	110		800	
V (aat)	Collector-Emitter Saturation		I _C = 10 mA, I _B = 0.5 mA		90	250	mV
V _{CE} (sat) Voltage			$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 5 \text{ mA}$		200	600	
		* Doog Coturation Valtage	I _C = 10 mA, I _B = 0.5 mA		700		
V _{BE} (sat) Collecto	r-Base Saturation Voltage	I _C = 100 mA, I _B = 5 mA		900		mV	
			$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	580	660	700	
V _{BE} (on) Base-Em	nitter On Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$			720	mV	
f _T	Current Gain Bandwidth Product		V _{CE} = 5 V, I _C = 10 mA, f = 100 MHz		300		MHz
C _{ob}	Output Capacitance		V _{CB} = 10 V, I _E = 0, f = 1 MHz		3.5	6.0	pF
C _{ib}	Input Capacitance		$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		9		pF
	NF Noise	BC846 / BC847 / BC848	V _{CF} = 5 V, I _C = 200 μA,		2.0	10.0	
NF		BC850	$R_G = 2 k\Omega, f = 1 kHz$		1.2	4.0	dB
Figure	BC850	$V_{CE} = 5$ V, I _C = 200 μA, R _G = 2 kΩ, f = 30 to 15000 Hz		1.4	3.0		

Note:

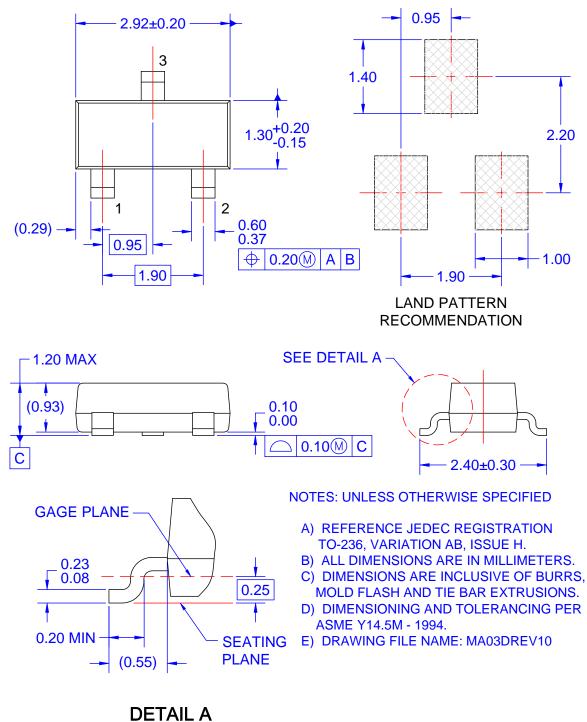
3. Pulse test: pulse width \leq 300 $\mu s,$ duty cycle \leq 2%

h_{FE} Classification

Classification	Α	В	С
h _{FE}	110 ~ 220	200 ~ 450	420 ~ 800

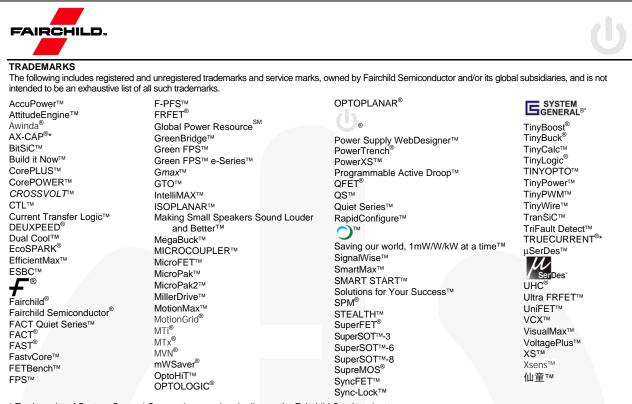


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